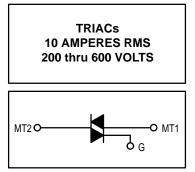
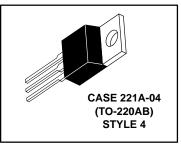
Triacs Silicon Bidirectional Triode Thyristors

... designed primarily for industrial and consumer applications for full wave control of ac loads such as appliance controls, heater controls, motor controls, and other power switching applications.

- Sensitive Gate Triggering in Three Trigger Modes for AC Triggering on Sinking Current Sources (MAC310 Series)
- Four Mode Triggering (10 mA) for Drive Circuits that Source Current (MAC310A Series)
- All Diffused and Glass-Passivated Junctions for Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Construction for Low Thermal Resistance, High Heat Dissipation
- Center Gate Geometry for Uniform Current Spreading

MAC310 Series MAC310A Series





MAXIMUM RATINGS ($T_C = 25^{\circ}C$ unless otherwise noted.)

Rating		Symbol	Value	Unit
Peak Repetitive Off-State Voltage ⁽¹⁾ (T _J = -40 to 1/2 Sine Wave 50 to 60 Hz, Gate Open)	110°C, MAC310-4, MAC310A4 MAC310-6, MAC310A6 MAC310-8, MAC310A8	VDRM	200 400 600	Volts
On-State RMS Current (T _C = 80°C) Full Cycle Sine Wave 50 to 60 Hz		^I T(RMS)	10	Amps
Peak Non-repetitive Surge Current (One Full Cycle 60 Hz, T _J = 110°C)		ITSM	100	Amps
Circuit Fusing (t = 8.3 ms)		l ² t	40	A ² s
Peak Gate Current (t $\leq 2 \mu s$)		IGM	±2	Amps
Peak Gate Voltage (t $\leq 2 \mu$ s)		V _{GM}	±10	Volts
Peak Gate Power (t $\leq 2 \mu$ s)		PGM	20	Watts
Average Gate Power (T _C = 80°C, t \leq 8.3 ms)		PG(AV)	0.5	Watts
Operating Junction Temperature Range		Тј	-40 to 110	°C
Storage Temperature Range		T _{stg}	-40 to 150	°C
Mounting Torque		_	8	in-lb

1. V_{DRM} for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

(continued)



MAC310 Series MAC310A Series

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit	
Thermal Resistance, Junction to Case	R _{θJC}	2.2	°C/W	
Thermal Resistance, Junction to Ambient	R _{θJA}	60	°C/W	

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ and either polarity of MT2 to MT1 voltage unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
Peak Blocking Current $T_J = 25^{\circ}C$ $(V_D = Rated V_{DRM}, T_J = 110^{\circ}C)$	IDRM	_		10 2	mA
Peak On-State Voltage (ITM = 14 A Peak, Pulse Width \leq 2 ms, Duty Cycle \leq 2%)	VTM	-	-	2	Volts
Gate Trigger Current (Continuous dc) $(V_D = 12 V, R_L = 100 \Omega)$ MT2(+), G(+); MT2(+), G(-); MT2(-), G(-) MT2(-), G(+) "A" Suffix Only	IGT		_	5 10	mA
Gate Trigger Voltage (Continuous dc) $(V_D = 12 V, R_L = 100 \Omega)$ MT2(+), G(+); MT2(+), G(-); MT2(-), G(-) MT2(-), G(+) "A" Suffix Only $(V_D = Rated V_{DRM}, T_C = 110^{\circ}C, R_L = 10 k)$ All Trigger Modes	V _{GT}	 0.2		2 2.5 —	Volts
Holding Current (V _D = 12 V, I _{TM} = 200 mA, Gate Open)	Ч	—	—	15	mA
Gate-Controlled Turn-On Time (V_D = Rated V_{DRM} , I _{TM} = 14 A Peak, I _G = 30 mA)	^t gt	—	1.5	-	μs
Critical Rate of Rise of Off-State Voltage (V _D = Rated V _{DRM} , Exponential Waveform, T _C = 110°C)	dv/dt	—	25	-	V/µs
Critical Rate of Rise of Commutation Voltage (V _D = Rated V _{DRM} , I _{TM} = 14 A Peak, Commutating di/dt = 5 A/ms, Gate Unenergized, T _C = 80°C)	dv/dt(c)	_	5	_	V/µs

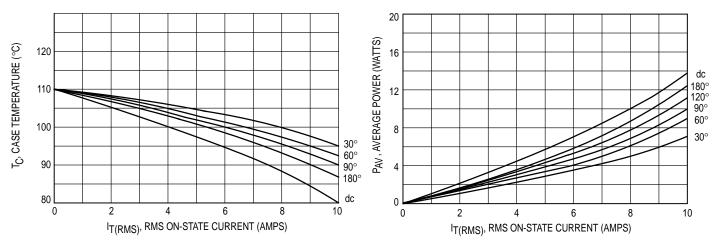
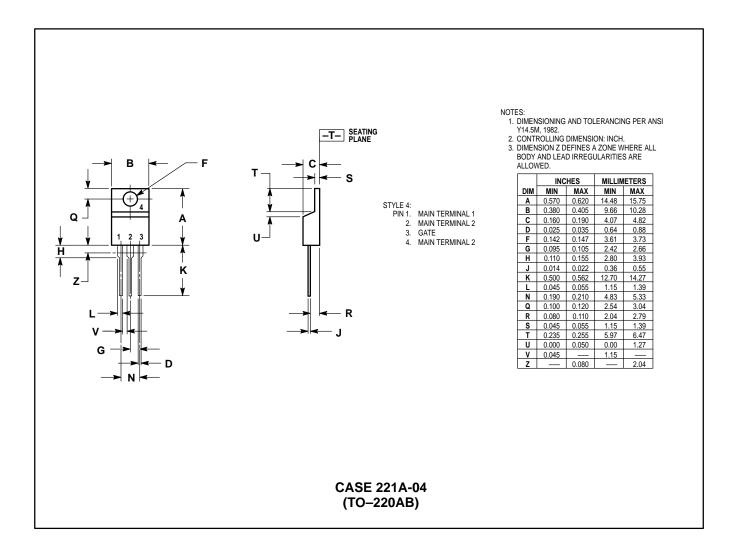




Figure 2. On-State Power Dissipation

PACKAGE DIMENSIONS



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